## **Homework Assignment No. 4**

Due on Wednesday, February 9, 2005

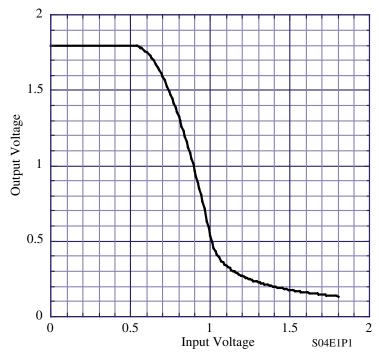
- 1.) Problem P4.2 of the text. (This problem should refer to Fig. P4.1 not Fig. P4.2) [Partial Answers: a.)  $V_{OH} = V_{DD}$  and  $V_{OL} = 0.055 \text{V}$  b.)  $V_{OH} = 0.733 \text{V}$ , and  $V_{OL} \approx 0.69 \text{V}$ , c.)  $V_{OH} = 1.11 \text{V}$  and  $V_{OL} = 0.69 \text{V}$ ]
- 2.) Problem P4.3 of the text. Use SPICE to confirm the results.

[Partial Answers:  $V_{IH} = 0.65$ V and  $V_{IL} = 0.55$ V]

3.) Problem P4.9 of the text.

[Answers:  $W_n = 0.2 \mu \text{m}, 0.1 \mu \text{m} \text{ and } 0.6 \mu \text{m}$ ]

4.) From the voltage transfer function curve shown, numerically identify,  $V_{OH}$ ,  $V_{OL}$ ,  $V_{IL}$ ,  $V_{IH}$ , and  $V_{S}$ . From these values, find the value of  $NM_{H}$  and  $NM_{L}$ .



5.) Given the layout for the NMOS transistor of Problem 2, find the value of  $C_{gs}$ ,  $C_{gd}$ ,  $C_{gb}$ ,  $C_{db}$ , and  $C_{sb}$  assuming that the junction depth of the source-drain diffusions is  $x_j = 50$  nm, m = 0.5 and the lateral diffusion is 10nm.

